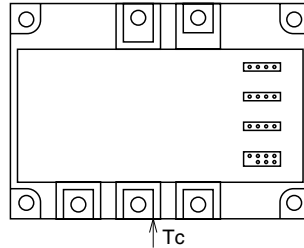


Symbol	Parameter	Condition	Ratings	Unit
V _{CES}	Collector-Emitter Voltage	V _D = 15V, V _{CIN} = 15V	600	V
±I _C	Collector Current	T _C = 25°C	200	A
±I _{CP}	Collector Current (Peak)	T _C = 25°C	400	A
P _C	Collector Dissipation	T _C = 25°C	541	W
T _j	Junction Temperature		-20 ~ +150	°C

Symbol	Parameter	Condition	Ratings	Unit
V _D	Supply Voltage	Applied between : V _{UP1} -V _{UPC} V _{VP1} -V _{VP} , V _{WP1} -V _{WP} , V _{N1} -V _N	20	V
V _{CIN}	Input Voltage	Applied between : U _P -V _{UPC} , V _P -V _{VP} , W _P -V _{WP} U _N • V _N • W _N -V _N	20	V
V _{FO}	Fault Output Supply Voltage	Applied between : U _{FO} -V _{UPC} , V _{FO} -V _{VP} , W _{FO} -V _{WP} FO-V _N	20	V
I _{FO}	Fault Output Current	Sink current at U _{FO} , V _{FO} , W _{FO} and FO terminal	20	mA

PM200CVA060**FLAT-BASE TYPE
INSULATED PACKAGE****TOTAL SYSTEM**

Symbol	Parameter	Condition	Ratings	Unit
V _{CC(Prot)}	Supply Voltage Protected by SC	V _D = 13.5 ~ 16.5V, Inverter Part, T _j = 125°C Start	400	V
V _{CC(surge)}	Supply Voltage (Surge)	Applied between : P-N, Surge value or without switching	500	V
T _c	Module Case Operating Temperature	(Note-1)	-20 ~ +100	°C
T _{stg}	Storage Temperature		-40 ~ +125	°C
V _{iso}	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base, AC 1 min.	2500	V _{rms}

(Note-1) T_c measurement point is below. (3mm depth at the center of the side of base plate)**ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise noted)****INVERTER PART**

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _D = 15V, I _C = 200A V _{CIN} = 0V	—	2.35	2.80	V
		T _j = 25°C T _j = 125°C	—	2.55	3.05	
V _{EC}	FWDi Forward Voltage	-I _C = 200A, V _D = 15V, V _{CIN} = 15V	—	2.20	3.30	V
t _{on}	Switching Time	V _D = 15V, V _{CIN} = 0V↔15V V _{CC} = 300V, I _C = 200A T _j = 125°C Inductive Load (upper and lower arm)	0.4	0.8	2.1	μs
t _{rr}			—	0.2	0.3	
t _{c(on)}			—	0.3	1.1	
t _{off}			—	1.8	2.9	
t _{c(off)}			—	0.6	1.2	
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = V _{CES} , V _{CIN} = 15V	—	—	1	mA
		T _j = 25°C T _j = 125°C	—	—	10	

CONTROL PART

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
I _D	Circuit Current	V _D = 15V, V _{CIN} = 15V	—	40	55	mA
				13	18	
V _{th(ON)}	Input ON Threshold Voltage	Applied between : UP-VU _{PC} , VP-VV _{PC} , WP-VW _{PC}	1.2	1.5	1.8	V
V _{th(OFF)}	Input OFF Threshold Voltage	UN • VN • WN-VNC	1.7	2.0	2.3	
SC	Short Circuit Trip Level	-20 ≤ T _j ≤ 125°C, V _D = 15V	310	—	—	A
t _{off(SC)}	Short Circuit Current Delay Time	V _D = 15V	—	10	—	μs
OT	Over Temperature Protection	Base-plate Temperature detection, V _D = 15V	Trip level	111	118	°C
OT _r			Reset level	—	100	
UV	Supply Circuit Under-Voltage Protection	-20 ≤ T _j ≤ 125°C	Trip level	11.5	12.0	V
UV _r			Reset level	—	12.5	
I _{FO(H)}	Fault Output Current	V _D = 15V, V _{FO} = 15V (Note-2)	—	—	0.01	mA
I _{FO(L)}			—	10	15	
t _{FO}	Minimum Fault Output Pulse Width	V _D = 15V (Note-2)	1.0	1.8	—	ms

(Note-2) Fault output is given only when the internal SC, OT & UV protection.

Fault output of OT protection operate by lower arm

Fault output of OT, UV protection given pulse while over level.

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THERMAL RESISTANCES

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
R _{th(j-c)Q}	Junction to case Thermal	Inverter IGBT part (per 1/6 module)	—	—	0.231	°C/W
R _{th(j-c)F}	Resistances	Inverter FWDi part (per 1/6 module)	—	—	0.35	
R _{th(c-f)}	Contact Thermal Resistance	Case to fin, Thermal grease applied (per 1 module)	—	—	0.022	

MECHANICAL RATINGS AND CHARACTERISTICS

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
—	Mounting torque	Mounting part screw : M5	2.5	3.0	3.5	N • m
—	Mounting torque	Main terminal screw : M5	2.5	3.0	3.5	N • m
—	Weight		—	730	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Test Condition	Recommended value	Unit
V _{CC}	Supply Voltage	Applied across P-N terminals	≤ 400	V
V _D	Control Supply Voltage	Applied between : V _{UP1} -V _{UPC} , V _{VP1} -V _{VPC} V _{WP1} -V _{WPC} , V _{N1} -V _{NVC} (Note-3)	15 ± 1.5	V
V _{CIN(ON)}	Input ON Voltage	Applied between : U _P -V _{UPC} , V _P -V _{VPC} , W _P -V _{WPC} U _N • V _N • W _N -V _{NVC}	≤ 0.8	V
V _{CIN(OFF)}	Input OFF Voltage		≥ 4.0	
t _{dead}	Arm Shoot-through Blocking Time	For IPM's each input signals	≥ 2.5	μs
f _{PWM}	PWM Input Frequency	Using Application Circuit input signal of IPM, 3φ Sinusoidal PWM VVVF inverter	≤ 20	kHz

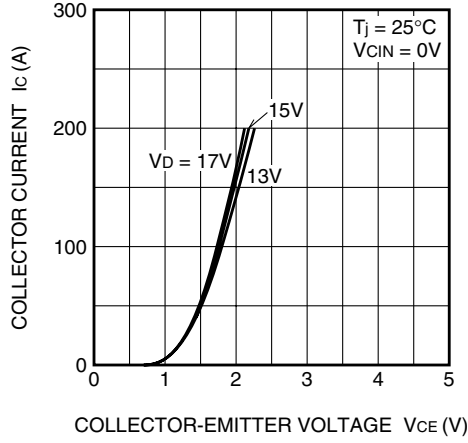
(Note-3) With ripple satisfying the following conditions dv/dt swing ≤ ±5V/μs, Variation ≤ 2V peak to peak

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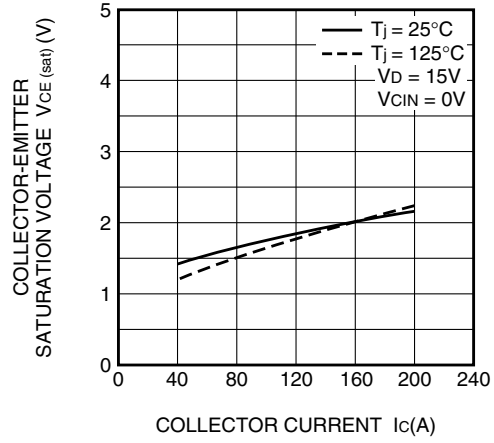
FLAT-BASE TYPE
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PERFORMANCE CURVES

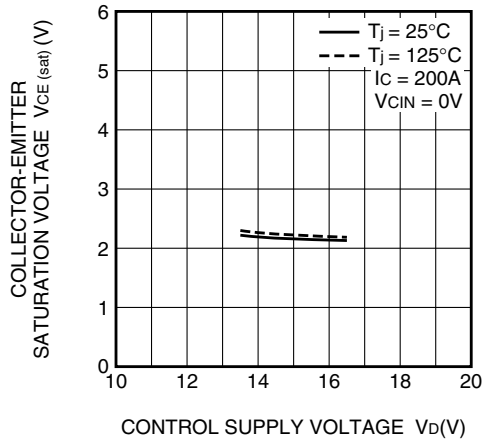
OUTPUT CHARACTERISTICS
(TYPICAL)



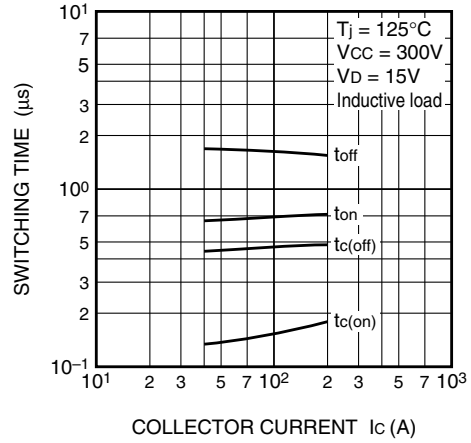
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



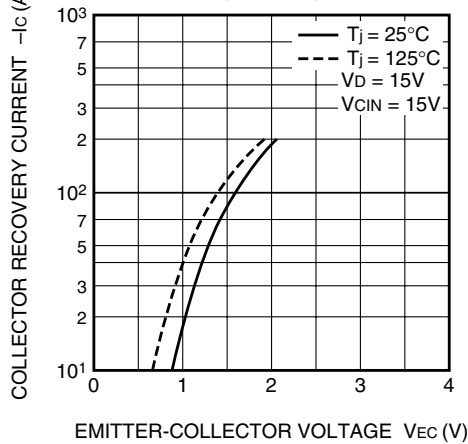
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



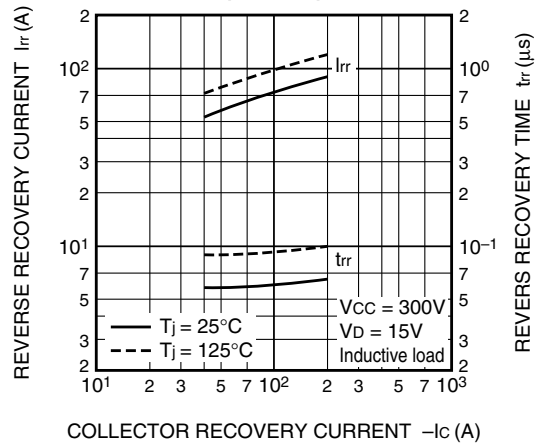
SWITCHING CHARACTERISTICS
(TYPICAL)



DIODE FORWARD CHARACTERISTICS
(TYPICAL)



DIODE REVERSE RECOVERY CHARACTERISTICS
(TYPICAL)



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